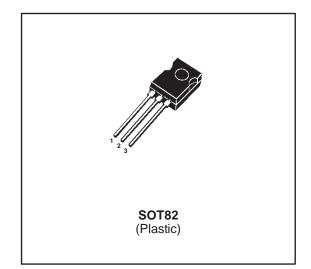


FIRE LIGHTER CIRCUIT

Application Specific Discretes A.S.D.TM

FEATURES

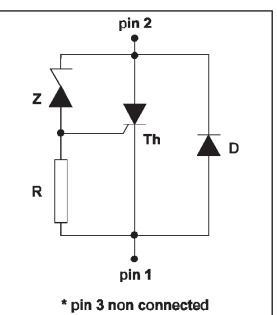
- SPACE SAVING : MONOLITHIC FIRE LIGHTER FUNCTION INTEGRATION
- DEDICATED THYRISTOR STRUCTURE FOR CAPACITANCE DISCHARGE IGNITION OPERATION
- HIGH PULSE CURRENT CAPABILITY 190A @ tp = 10μs



FUNCTIONAL DIAGRAM

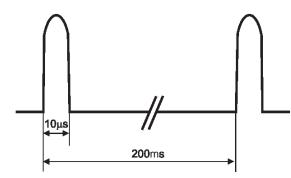


- The FLC01 is a high performance planar diffused technology adapted to high temperature and rugged environmental conditions.
- It has been developed especially for capacitance discharge operation. The main applications are gas lighter or ignitor such as : cookers/gas boilers/gas hobs...
- Th: Thyristor for switching operation.
- Z : Zener diode to set the threshold voltage.
- D : Diode for reverse conduction.
- R : 2 k Ω resistor.



Symbol	Parameter	Value	Unit	
Itrm	Repetitive surge peak on state current for thyristor	190	А	
IFRM	Repetitive surge peak on state current for diode			
di/dt	Critical rate of rise time on state current	120	A/μs	
Tstg Tj	Storage junction temperature range Maximum junction temperature	- 40 to + 150 + 125	°C	
Toper	er Operating temperature range			°C
TL	TL Maximum lead temperature for soldering during 10s			°C

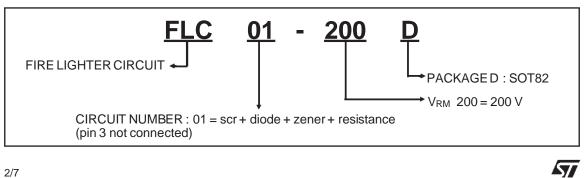
Note 1 : Test current waveform



THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rth(j-a)	Thermal resistance junction to ambient	100	°C/W

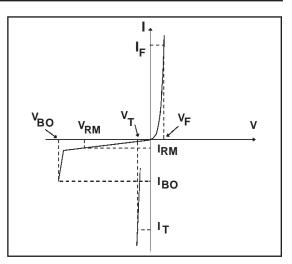
ORDERING INFORMATION



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ELECTRICAL CHARACTERISTICS

Symbol Parameters		
V _{RM}	Stand-off voltage	
VBO	Breakovervoltage	
VT	On-state voltage	
VF	Diode voltage drop	
I _{BO}	Breakovercurrent	
Irm	Leakage current	
αΤ	Thermal coefficient for V_{BO}	



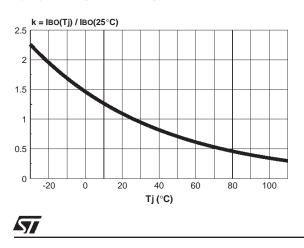
DIODE (D) PARAMETER

Symbol	Test Conditions				Value	Unit
VF	$I_F = 2A$	$tp \le 1 ms$	Tj = 25℃	MAX	1.7	V

THYRISTOR (Th) and ZENER (Z) PARAMETERS

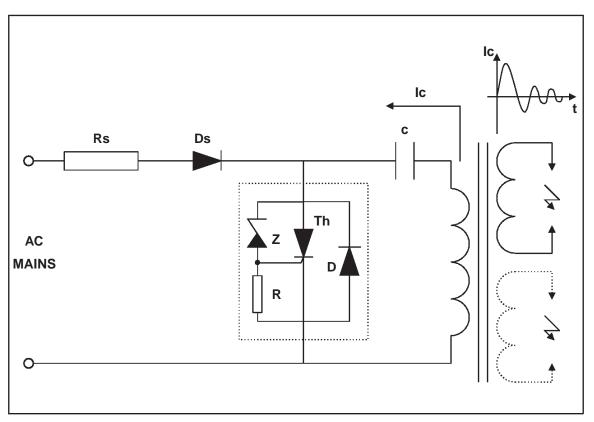
Symbol	Test conditions		Min	Тур	Мах	Unit
I _{RM}	V _{RM} = 200 V	Tj = 25℃			1	μΑ
		Tj = 125℃			10	μΑ
V _{BO}	at I _{BO}	Tj = 25°C	206	220	233	V
I _{BO}	at V _{BO}	Tj = 25°C			0.5	mA
VT	$I_T = 2A$ tp $\leq 1ms$	Tj = 25°C			1.7	V
αΤ				0.27		V/∘C

Fig.1 : Relative variation of breakover current (I_{BO}) versus junction temperature



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BASIC APPLICATION



The applications of the lighter using the capacitance discharge topology operate in 2 phases:

PHASE 1

The energy coming from the mains is stored into the capacitor C. For that, the AC voltage is rectified by the diode Ds.

PHASE 2

At the end of the phase 1, the voltage across the capacitor C reaches the avalanche threshold of the zener. Then a current flows through the gate of the thyristor Th which fires.

The firing of the thyristor causes an alternating current to flow through the capacitor C.

The positive parts of this current flow through C, Th and the primary of the HV transformer.

The negative parts of the current flow through C, D and the primaty of the HV transformer.

RS RESISTOR CALCULATION

The Rs resistor allows, in addition with the capacitor C, to adjust the spark frequency and to limitate the current from the mains. Its value shall allow the thyristor Th to fire even in the worst case. In this borderline case the system must fire with the lower RMS mains voltage value while the breakdown voltage and current of the FLC are at the maximum.

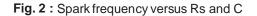
The maximum Rs value is equal to :

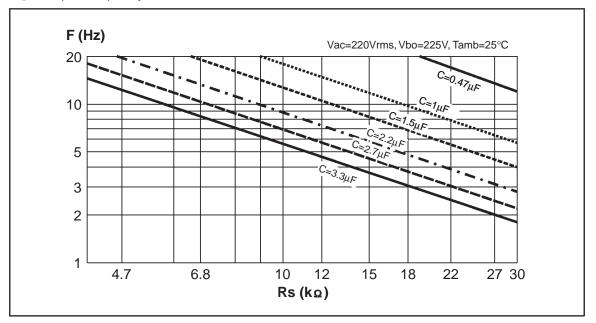
 $Rsmax = \frac{(V_{AC} \min \sqrt{2}) - [V_{BO} \max .(1 + \alpha T.(T_{amb} - 25))]}{k \cdot I_{BO} *}$

*: see fig 1

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The couple Rs/C can be chosen with the previous curve. Keep in mind the Rs maximum limit for which the system would not work when the AC

mains is minimum. The next curve shows the behavior with Rs=15 k Ω and C=1 $\mu F.$

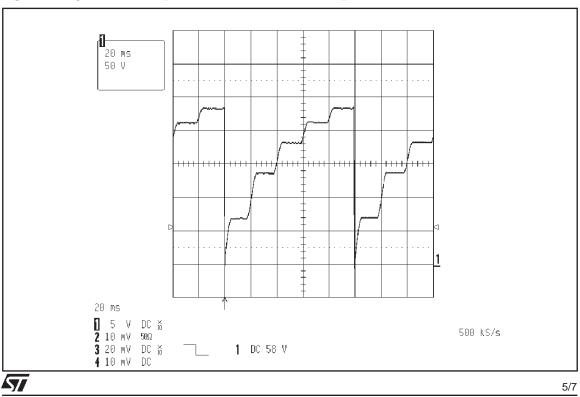


Fig. 3 : Voltage across the capacitance with Rs = $15k\Omega$, C = 1μ F and V_{BO} = 225V.

PEAK CURRENT LIMIT

This component is designed to withstand I_{TRM} = 150A for a pulse duration of 10 μs for an

Fig. 4 : Peak current limit

ITRM (A) Tjmax =125°C 190 180 170 160 150 140 130 120 110 6 8 10 12 14 tp (μs)

POWER LOSSES (For 10µs, see note 1)

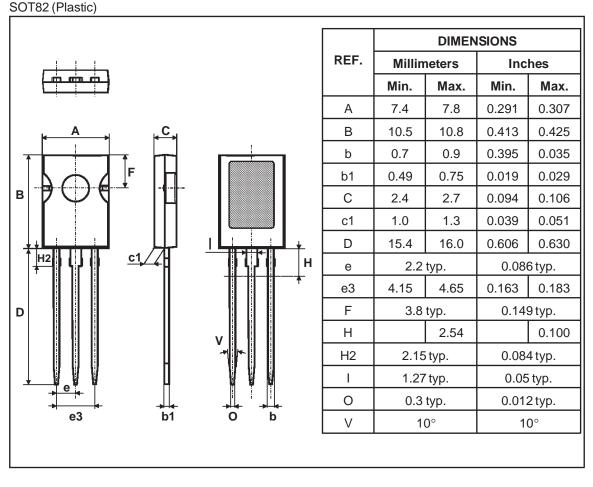
To evaluate the power losses, please use the following equations:

For the thyristor : $P = 1.18 \times I_{T(AV)} + 0.035 I^2_{T(RMS)}$ For the diode : $P = 0.67 \times I_{F(AV)} + 0.106 I^2_{F(RMS)}$



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PACKAGE MECHANICAL DATA



- Marking: type number
- Weight: 0.72 g.

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